NSN 5961-01-300-9835

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-300-9835 **Inclosure Material:** Ceramic **Overall Length:** 0.870 inches **Terminal Length:** 0.145 inches **Overall Height:** 0.180 inches **Overall Width:** 0.260 inches **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage, dc all transistor and 15.0 collector to emitter voltage, dc all transistor and 4.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 95.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0